DATA SHEET



MOS INTEGRATED CIRCUIT $\mu PD4726$

RS-232 LINE DRIVER/RECEIVER

The μ PD4726 is a high-voltage silicon gate CMOS line driver/receiver conforming to EIA/TIA-232-E Standards. It contains a DC/DC converter and can operate with a +5 V single power supply. In addition, it is also provided with ancillary functions such as a standby function.

This IC is equipped with four driver circuits and seven receiver circuits and can configure a simple RS-232 interface circuit with only four external capacitors.

FEATURES

- Conforms to EIA/TIA-32-E (old RS-232C) Standards
- +5 V single power supply
- A standby mode can be set by making the standby pin low to reduce the power dissipation. At this time, the driver outputs go into a high-impedance state.
- Two receiver circuits can operate as inverters without a hysteresis width even in the standby mode. The remaining five receiver circuits are fixed to the high level.

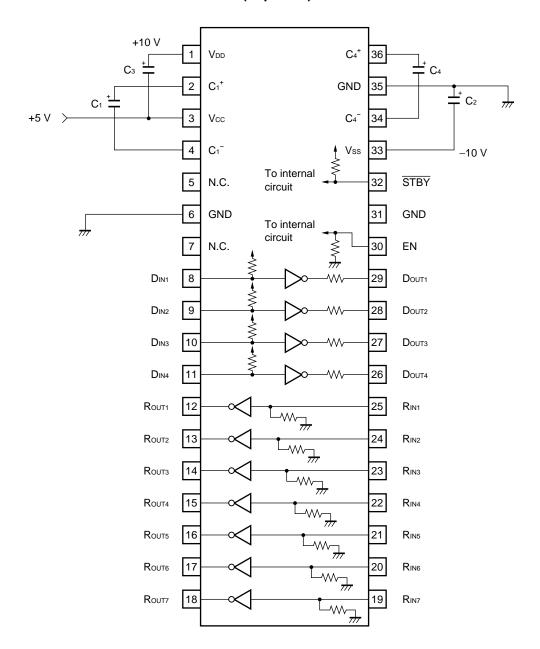
ORDERING INFORMATION

Part Number	Package	Quality Grade
μPD4726GS-BAF	36-pin plastic SSOP (300 mil)	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.



BLOCK DIAGRAM/PIN CONFIGURATION (Top View)



Notes 1. VDD and Vss output internally boosted voltages. Do not connect a load directly to these pins.

- 2. It is recommended that capacitors having a breakdown voltage of 20 V or higher be used as C_1 through C_5 . Inserting a bypass capacitor of 0.1 to 1 μ F in between Vcc and GND is also recommended.
- 3. Be sure to connect all the GND pins. Especially, make sure that pin 31 is connected; otherwise, the μ PD4726 will not operate normally. Be sure to leave the NC pins (pins 5 and 7) open.
- **4.** The pull-up resistors for D_{IN1} through D_{IN4} and STBY and the pull-down resistor for EN are active resistors.



TRUTH TABLE

Drivers

STBY	Din	D оит	Remarks
L	×	Z	Standby mode (DC/DC converter stops.)
Н	L	Н	Space level output
Н	Н	L	Mark level output

Receivers

STBY	EN	R	Rin		DUT	Remarks	
SIDI	LIN	R6 - R7	R1 - R5	R6 - R7	R1 - R5	Remains	
L	L	×	×	Н	Н	Standby mode 1 (DC/DC converter stops.)	
L	Н	L	×	Н	Н	Standby mode 2 (DC/DC converter stops. R ₆ and R ₇ operate.)	
L	Н	Н	×	L	Н		
Н	×	L	L H		1	Mark level input	
Н	×	Н		I	L	Space level input	

H: high levelL: low level

Z: high impedance

×: H or L



ABSOLUTE MAXIMUM RATING (Ta = 25 °C)

Parameter	Symbol	Ratings	Unit
Supply voltage	Vcc	-0.5 to +7.0	>
Driver input voltage	Din	-0.5 to Vcc + 0.5	V
Receiver input voltage	Rin	-30.0 to +30.0	V
Control input voltage (STBY, EN)	Vin	−0.5 to Vcc + 0.5	V
Driver output voltage	D оит	-25.0 to +25.0 Note 5	V
Receiver output voltage	Rоит	-0.5 to Vcc + 0.5	V
Input current (D _{IN} , STBY, EN)	lini	±20.0	mA
Operating ambient temperature	T _{opt} .	-40 to +85	ů
Storage temperature	T _{stg.}	–55 to +150	ĵ
Permissible package power dissipation	Рт	0.5	W

Note 5. Pulse width: 1 ms, duty cycle: 10 % MAX.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply voltage (Vcha = L)	Vcc	4.5	5.0	5.5	V
Input voltage, high (D _{IN})	ViH	2.0		Vcc	V
Input voltage, low (D _{IN})	VIL	0		0.8	V
Input voltage, high (STBY, EN)	ViH	2.4		Vcc	V
Input voltage, low (STBY, EN)	VIL	0		0.8	V
Receiver input voltage	Rın	-30		+30	V
Operating ambient temperature	T _{opt} .	-40		+85	°C
External capacitance (nominal value)	Note 6	1		4.7	μF

Note 6. Use capacitors whose capacitance fluctuation is within ± 50 % including fluctuations due to temperature and tolerance (effective value: 0.5 to 7.05 μ F).

Use of capacitors with excellent high-frequency characteristics (such as multilayer ceramic capacitors, tantalum capacitors, and aluminum electrolytic capacitors for switching power supply) is recommended. Keep the wiring length between a capacitor and an IC pin as short as possible.



ELECTRICAL SPECIFICATIONS (CHIP)

(Unless otherwise specified, Ta = -40 to +85 °C, C1 through C5 = 1 μ F)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Circuit current	Icc1	$Vcc = +5.0 \text{ V}$, no load, R _{IN} pin open, $\overline{\text{STBY}} = \text{H}$			12	mA
Circuit current	Icc2	$\begin{aligned} &\text{Vcc} = +5.0 \text{ V, } \text{RL} = 3 \text{ k}\Omega \text{ (Dout),} \\ &\underline{\text{DIN}} = \text{GND, } \text{RIN, } \text{Rout pins open,} \\ &\overline{\text{STBY}} = \text{H} \end{aligned}$			38	mA
Circuit current in standby mode (standby mode 1)	Icc3	Vcc = +5.0 V, no load, D_{IN} , R_{IN} pins open, \overline{STBY} = L, EN = L, T_a = 25 °C		9	20	μΑ
		Vcc = +5.0 V, no load, D _{IN} , R _{IN} pins open, $\overline{\text{STBY}}$ = L, EN = L,		15		μΑ
Circuit current in standby mode (standby mode 2)	Icc4	Vcc = +5.0 V, no load, DIN, RIN pins open, \overline{STBY} = L, EN = H, Ta = 25 °C		9	20	μΑ
		Vcc = +5.0 V, no load, DIN, RIN pins open, $\overline{\text{STBY}}$ = L, EN = H, Ta = 25 °C		15		μΑ
Input voltage, high	VIH	STBY, EN pins, Vcc = +4.5 to +5.5 V	2.4			V
Input voltage, low	VIL	STBY, EN pins, Vcc = +4.5 to +5.5 V			0.8	V
Input current, high	Іін	STBY pin, Vcc = +5.5 V, Vı = +5.5 V			1	μΑ
Input current, low	lıL	STBY pin, Vcc = +5.5 V, Vı = 0 V			-40	μΑ
Input current, high	Іін	EN pin, Vcc = +5.5 V, Vı = +5.5 V			40	μΑ
Input current, low	lıL	EN pin, Vcc = +5.5 V, Vı = 0 V			-1	μΑ
Input capacitance	Cin	Driver inputs and receiver inputs, Vcc = +5.0 V, vs. GND, f = 1 MHz			10	pF

Remark TYP. value is a reference value at $T_a = 25$ °C.



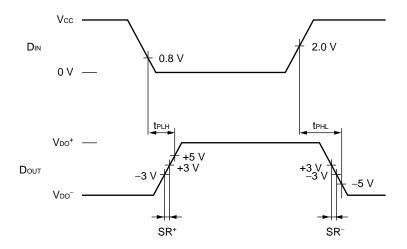
ELECTRICAL SPECIFICATIONS (DRIVERS)

(Unless otherwise specified, T_a = -40 to +85 °C, Vcc = +5.0 V \pm 10 %, C₁ through C₅ = 1 μ F)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage, low	VIL				0.8	V
Input voltage, high	ViH		2.0			V
Input current, low	lıL				-40	μΑ
Input current, high	lін				1.0	μΑ
Output voltage	VDO	$Vcc = +5.0 \text{ V}, \text{ RL} = \infty, \text{ Ta} = 25 ^{\circ}\text{C}$		±9.7		V
		Vcc = +5.0 V, R _L = 3 k Ω , T _a = T _{opt} .	±5.5			V
		Vcc = +4.5 V, R_L = 3 k Ω , T_a = T_{opt} .	±5.0			V
Output short current	Isc	Vcc = +5.0 V, vs. GND			±40	mA
Slew rate	SR	$C_L = 10 \text{ pF}, R_L = 3 \text{ to } 7 \text{ k}\Omega$	4.0		30	V/μs
		$C_L = 2 500 \text{ pF}, R_L = 3 \text{ to } 7 \text{ k}\Omega$	4.0		30	V/μs
Propagation delay time Note 8	t _{PHL}	$R_L = 3 \text{ k}\Omega$, $C_L = 2 500 \text{ pF}$		2		μs
Output resistance	R₀	$V_{CC} = V_{DD} = V_{SS} = 0 V$ $V_{OUT} = \pm 2 V$	300			Ω
Standby output transition time	t DAZ	$R_L = 3 \text{ k}\Omega, C_L = 2500 \text{ pF}, Note 9$		4	10	μs
Standby output transition time	t dza	$R_L = 3 \text{ k}\Omega, C_L = 2500 \text{ pF}, Note 9$		0.5	1	ms
Power-ON output transition time	t PRA	$R_L = 3 \text{ k}\Omega, C_L = 2500 \text{ pF}, Note 10$		0.5	1	ms

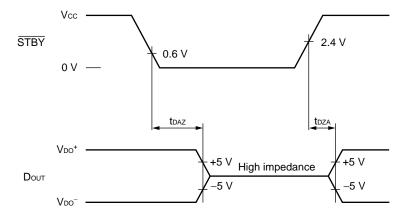
Remark TYP. value is a reference value at $T_a = 25$ °C.

Note 8. Test point



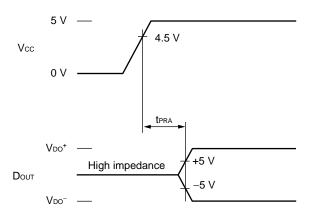


Note 9. Test point



The driver output is undefined during the standby output transition time toza. Do not perform communication within the standby output transition time toza after the standby mode has been released.

Note 10. Test point



The driver output is undefined during the power-ON output transition time tpra. Do not perform communication within the power-ON output transition time tpra on power application.



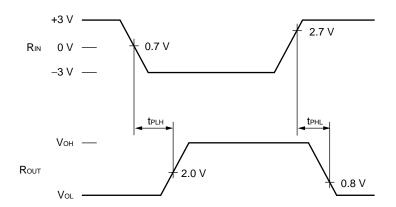
ELECTRICAL SPECIFICATIONS (RECEIVERS)

(Unless otherwise specified, Vcc = 4.5 to 5.5 V, T_a = -40 to +85 °C, C₁ through C₅ = 1 μ F)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output voltage, low (STBY = H)	Vol1	louτ = 4 mA			0.4	V
Output voltage, high (STBY = H)	Vон1	Iouτ = −4 mA	Vcc - 0.4			V
Output voltage, low (STBY = L)	Vol2	louτ = 4 mA			0.5	V
Output voltage, high (STBY = L)	V _{OH2}	Iouτ = -4 mA	Vcc - 0.5			V
Propagation delay time (STBY = H)	tphL tpLH	$R_{IN} \rightarrow R_{OUT}, C_L = 150 pF$ $V_{CC} = +4.5 V, N_{OIE} 11$		0.2		μs
Propagation delay time (STBY = L, EN = H)	tphl tplh	$\begin{array}{c} \text{Rin} \rightarrow \text{Rout (R}_6, \text{R}_7), \text{CL} = &150 \text{ pF} \\ \text{Vcc} = &+4.5 \text{ V}, ^{\text{Note 11}} \end{array}$		0.1		μs
Propagation delay time (STBY = L)	t _{PHA} t _{PAH}	$\begin{split} EN &\rightarrow \text{Rout (R6, R7), CL =150 pF} \\ Vcc &= +4.5 \text{ V, } \\ \text{Note 12} \end{split}$		100	300	ns
Input resistance	Rı		3	5.5	7	kΩ
Open voltage across input pins	Vio				0.5	V
Input threshold voltage	ViH	Vcc = +4.5 to +5.5 V	1.7	2.3	2.7	V
$\overline{(STBY} = H)$	VIL	Vcc = +4.5 to +5.5 V	0.7	1.1	1.7	V
	Vн	Vcc = +4.5 to +5.5 V (hysteresis width)	0.5	1.2	1.8	V
Input threshold voltage	ViH	Vcc = +4.5 to +5.5 V, Rin6, Rin7	2.7	1.5		V
$(\overline{STBY} = L, EN = H)$	VIL	Vcc = +4.5 to +5.5 V, Rin6, Rin7		1.5	0.7	V
Standby output transition time	t dah	Note 13		0.2	3	μs
Standby output transition time	t dha	Note 13		0.3	1	ms
Power-ON output transition time	t PRA	Note 14		0.5	1	ms

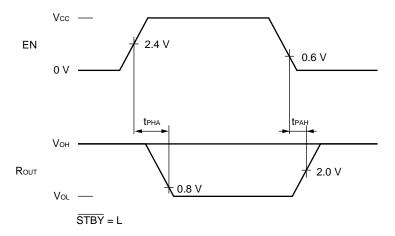
Remark TYP. value is a reference value at $T_a = 25$ °C.

Note 11. Test point

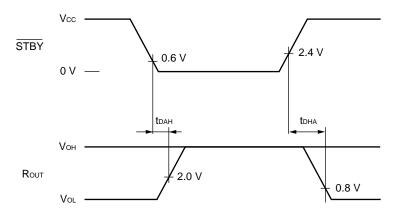




Note 12. Test point

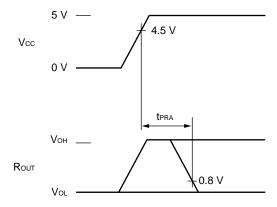


Note 13. Test point



The receiver output is undefined during the standby output transition time t_{DHA}. Do not perform communication within the standby output transition time t_{DHA} after the standby mode has been released.

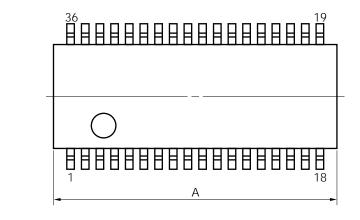
Note 14. Test point



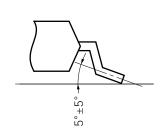
The receiver output is undefined during the power-ON output transition time tpra. Do not perform communication within the power-ON output transition time tpra on power application.

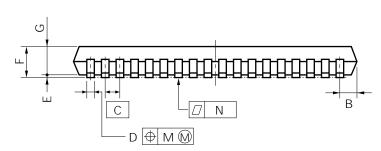


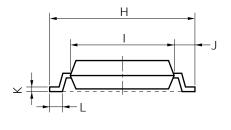
36 PIN PLASTIC SHRINK SOP (300 mil)











NOTE

Each lead centerline is located within 0.10 mm (0.004 inch) of its true position (T.P.) at maximum material condition.

P36GM-80-300B-3

ITEM	MILLIMETERS	INCHES
А	15.54 MAX.	0.612 MAX.
В	0.97 MAX.	0.039 MAX.
С	0.8 (T.P.)	0.031 (T.P.)
D	0.35 ^{+0.10} _{-0.05}	0.014+0.004
E	0.125±0.075	0.005±0.003
F	1.8 MAX.	0.071 MAX.
G	1.55	0.061
Н	7.7±0.3	0.303±0.012
I	5.6	0.220
J	1.1	0.043
K	$0.20^{+0.10}_{-0.05}$	$0.008^{+0.004}_{-0.002}$
L	0.6±0.2	0.024+0.008
М	0.10	0.004
N	0.10	0.004



RECOMMENDED SOLDERING CONDITIONS

Solder and mount the μ PD4726 under the following recommended conditions. Consult NEC for conditions other than those recommended.

μ PD4726GS-BAF

Soldering method	Soldering conditions	Symbol
Infrared ray reflow	Peak temperature of package surface: 235 °C, Reflow time: Within 30 sec (210 °C or higher), Number of reflow process: 2, Exposure limit: None Note	IR35-00-2
VPS	Peak temperature of package surface: 215 °C, Reflow time: Within 40 sec (200 °C or higher), Number of reflow process: 2, Exposure limit: None Note	VP15-00-2
Wave soldering	Solder temperature: 260 °C or lower, Reflow time: Within 10 sec, Number of reflow process: 1, Exposure limit: None Note	WS60-00-1
Partial heating	Pin temperature: 300 °C or lower, Time: Within 10 sec, Exposure limit: None Note	

Note Exposure limit before soldering after dry-package is opened. Storage condition: 25 °C and relative humidity at 65 % or less.

Caution Do not use two or more soldering methods in combination (except the partial heating method).

REFERENCE

Document name	Document No.
Semiconductor Device Mounting Technology Manual	IEI-1207
Quality grade on NEC Semiconductor Devices	IEI-1209
NEC Semiconductor Device Reliability/Quality Control system	IEI-1212

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Anti-radioactive design is not implemented in this product.

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